

**KEY PARAMETERS** 

2800V

1960A

31250A

 $\mathbf{V}_{\text{RRM}}$ 

 $\boldsymbol{I}_{\text{F(AV)}}$ 

FSM



### **APPLICATIONS**

- Rectification
- Freewheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

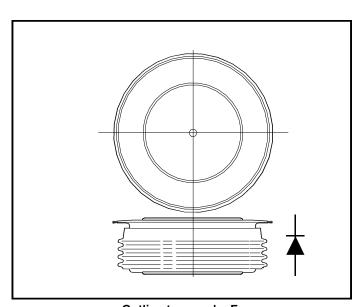
#### **FEATURES**

- Double Side Cooling
- High Surge Capability

### **VOLTAGE RATINGS**

Type Number	Repetitive Peak Reverse Voltage V	Conditions
TR2004SF28 TR2004SF27 TR2004SF26 TR2004SF25 TR2004SF24	2800 2700 2600 2500 2400	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.



Outline type code: F.
See Package Details for further information.

### **CURRENT RATINGS**

Symbol	Parameter	Conditions	Max.	Units			
Double Side Cooled							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 100°C	1960	Α			
I <sub>F(RMS)</sub>	RMS value	T <sub>case</sub> = 100°C	3077	Α			
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 100°C	2750	Α			
Single Side Cooled (Anode side)							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 100°C	1300	Α			
I <sub>F(RMS)</sub>	RMS value	T <sub>case</sub> = 100°C	2040	Α			
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 100°C	1600	Α			

# **TR2004SF**

## **SURGE RATINGS**

Symbol	Parameter	Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>case</sub> = 175°C	25.0	kA
l²t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 50% V <sub>RRM</sub> - 1/4 sine	3.12 x 10 <sup>6</sup>	A²s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>case</sub> = 175°C	31.25	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 0	4.88 x 10 <sup>6</sup>	A²s

# THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.022	°C/W
		Single side cooled	Anode dc	-	0.038	°C/W
			Cathode dc	-	0.052	°C/W
Б	Thermal resistance - case to heatsink	Clamping force 19.5kN with mounting compound	Double side	-	0.004	°C/W
$R_{th(c-h)}$			Single side	-	0.008	°C/W
	Virtual junction temperature	Forward (conducting)		-	185	°C
$T_{v_{j}}$		Reverse (blocking)		-	175	°C
T <sub>stg</sub>	Storage temperature range			-55	180	°C
-	Clamping force			18.0	22.0	kN

## **CHARACTERISTICS**

Symbol	Parameter	Conditions	Min.	Max.	Units
V <sub>FM</sub>	Forward voltage	At 3400A peak, T <sub>case</sub> = 25°C	-	1.3	V
I <sub>RRM</sub>	Peak reverse current	At V <sub>RRM</sub> , T <sub>case</sub> = 175°C -		50	mA
$Q_s$	Total stored charge	$I_F = 2000A$ , $dI_{RR}/dt = 3A/\mu s$ ,	-	2500	μС
I <sub>RR</sub>	Peak recovery current	$T_{case} = 175C, V_{R} = 100V$	-	105	А
V <sub>TO</sub>	Threshold voltage	At T <sub>vj</sub> = 175C	-	0.82	V
r <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 175C	-	0.16	mΩ

### **CURVES**

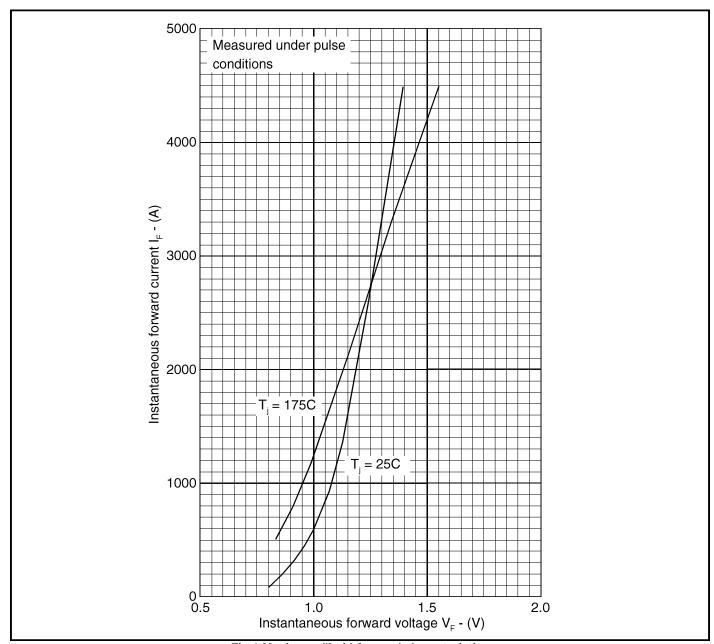


Fig.1 Maximum (limit) forward characteristics

## TR2004SF

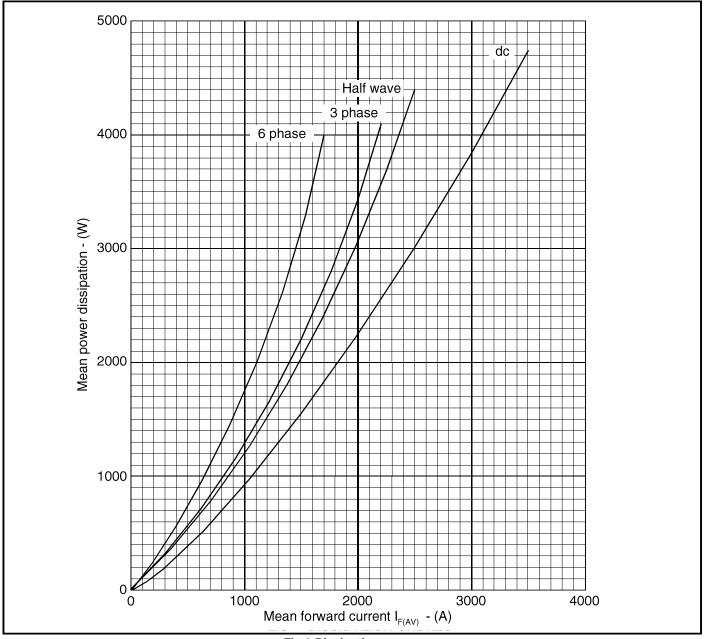


Fig.2 Dissipation curves

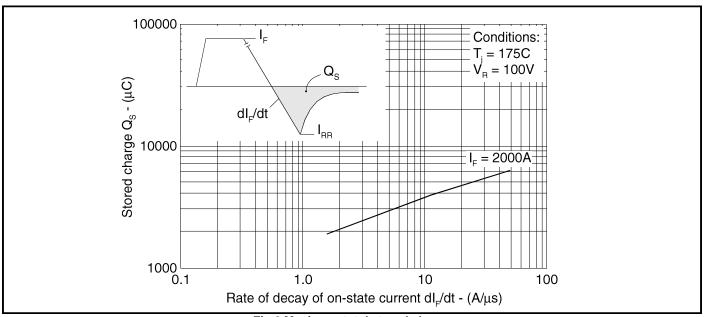


Fig.3 Maximum total stored charge

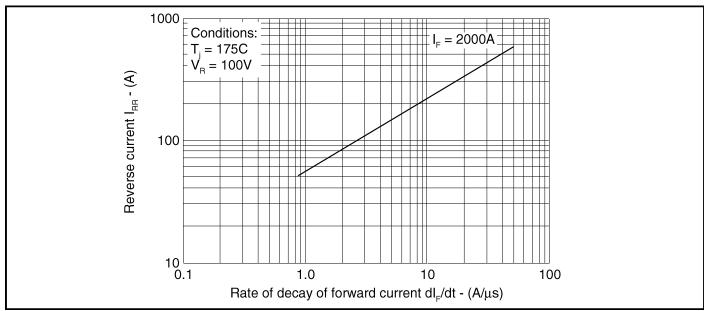


Fig.4 Maximum reverse recovery current

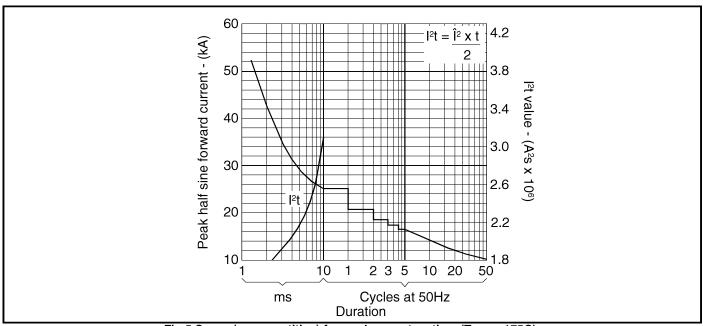


Fig.5 Surge (non-repetitive) forward current vs time  $(T_{case} = 175C)$ 

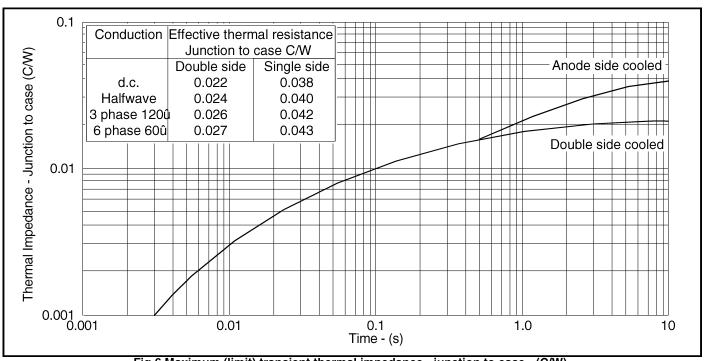


Fig.6 Maximum (limit) transient thermal impedance - junction to case - (C/W)

### **PACKAGE DETAILS**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

